

# Controlled Synthesis of 3D Nanostructures using Proximity-Field Nanopatterning Lithography and Graded Temperature ALD

SAND2008-6952C

Robert K. Grubbs

K.H.A Bogart, I. El-kady, K. Rahimian, R.A. Ellis, A.M. Sanchez,  
M. Wiwi, M.F. Su, C. Christodoulou, M. Reda-Taha

Sandia National Laboratories, Albuquerque, NM

D.L. Shir, J.A. Rogers

University of Illinois, Champaign-Urbana, IL



**214<sup>th</sup> ECS Meeting**  
**Honolulu, Hawaii**  
**October 14, 2008**



Sandia is a multiprogram laboratory operated by Sandia Corporation, a Lockheed Martin Company,  
for the United States Department of Energy under contract DE-AC04-94AL85000



# Outline

## What is Proximity-field nanoPatterning (PnP)?

- Creating 3D structures in SU8<sup>®</sup> photopolymer
- Phase mask geometry and resulting 3D structure
- ALD coating of nanostructures and different SU8<sup>®</sup>

## The Temperature Effect on 3D Polymer Nanostructures

- Optical methods for observing temperature stability
- ALD using *graded* and *constant* temperature

## Quartz Crystal Microbalance Results

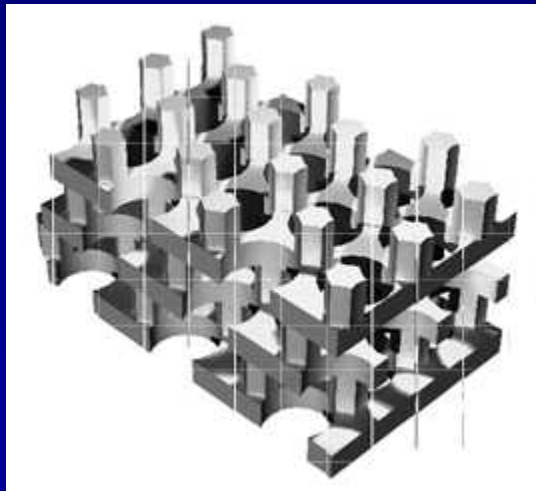
- Nucleation and growth of Al<sub>2</sub>O<sub>3</sub> on SU8<sup>®</sup> photopolymer
- QCM results from ALD on 3D nanostructures

## Example Depositions and Conclusions

# Periodic Three Dimensional Nanostructures

## *Present Methods*

- e-beam lithography
  - interference lithography
  - Opal self-assembly
- Resulting in: costly, slow  
poor yield, & limited  
geometries



*photonic lattice<sup>1</sup>*

## *Applications*

- photonic lattices
- catalyst supports
- micro electrodes
- filtration membranes
- metamaterials

## *Needed*

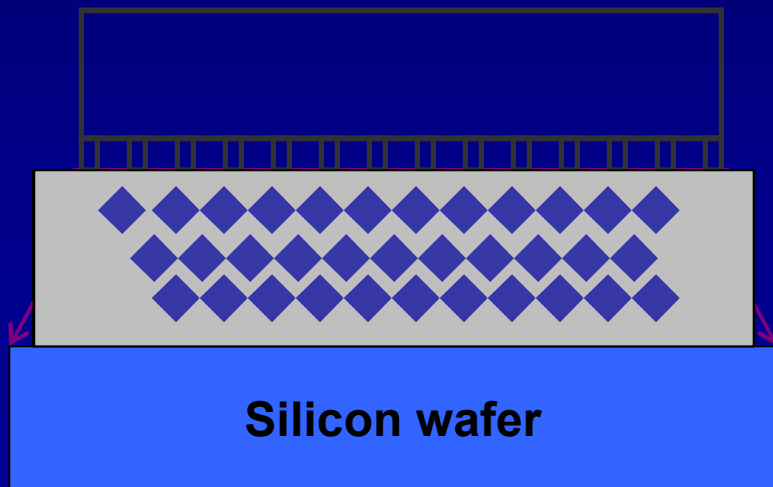
- Fast, cheap, simple equipment
- Large areas (long range order)
- Predictive / control
- High yield

# Proximity-field Nanopatterning (PnP)<sup>2</sup>

## The PnP Process:

1. Spincoat SU8<sup>®</sup> photopolymer
2. Apply phase mask
3. Expose sample with  $\lambda = 365$  nm
4. Develop out monomer

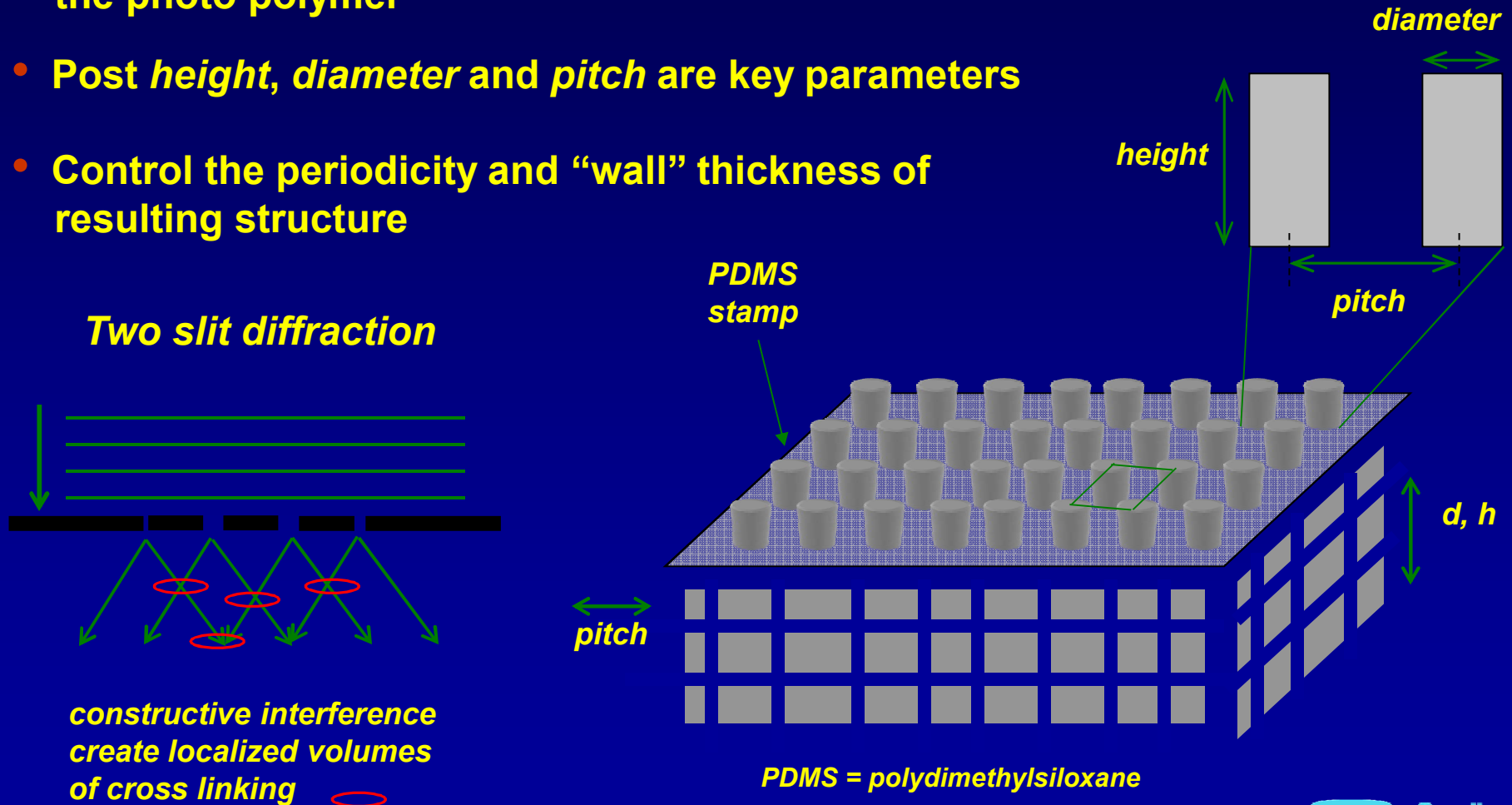
© MicroChem Corp



- SU8<sup>®</sup> has particular pre/ post bake and spin conditions
- Role of phase mask is important
- Exposure time is critical
- SU8<sup>®</sup> is a negative photo resist

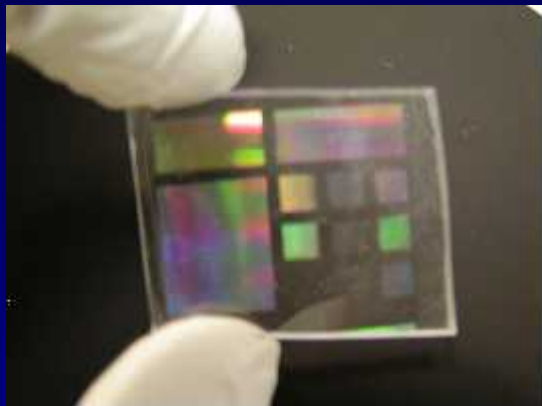
# Phase Mask Geometry Controls Resultant Nanostructure Shape

- The geometry of the phase mask is transferred to the photo polymer<sup>3</sup>
- Post *height*, *diameter* and *pitch* are key parameters
- Control the periodicity and “wall” thickness of resulting structure

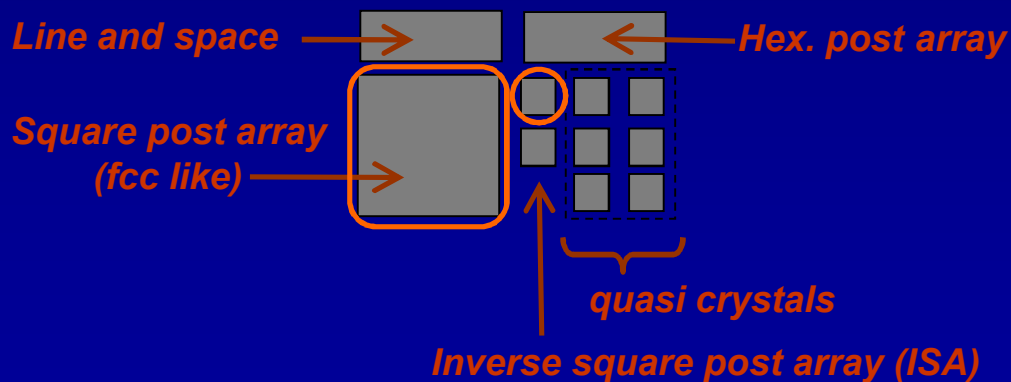
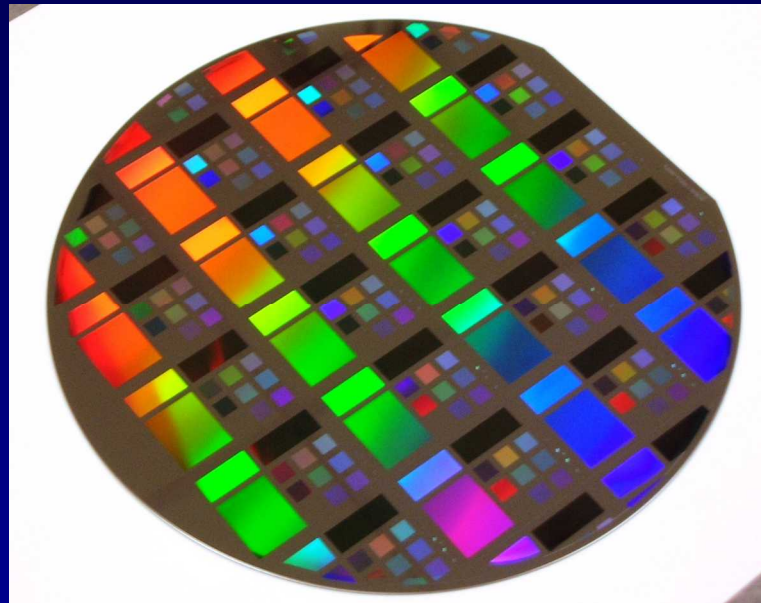


# Phase Mask Produces a Variety of Structures Across Six Inch Wafers

PDMS phase mask

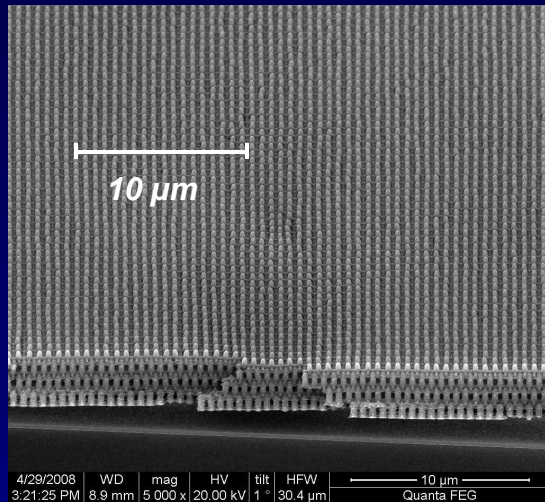


6 inch wafer of PnP nanostructures



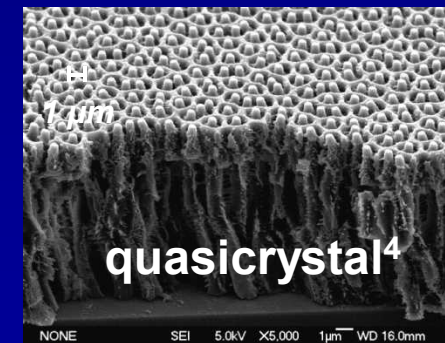
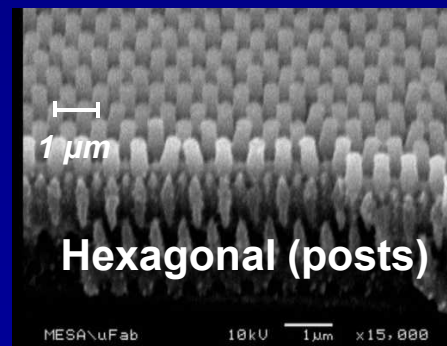
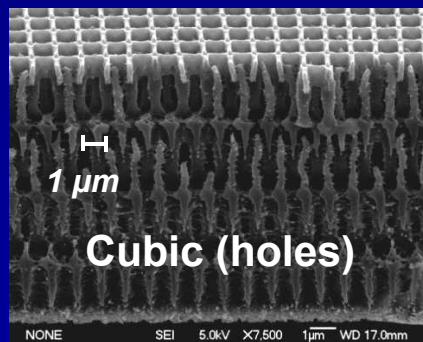
- Focus on two PnP structures: “fcc like” and ISA.

# SEM Images of Various PnP Structures



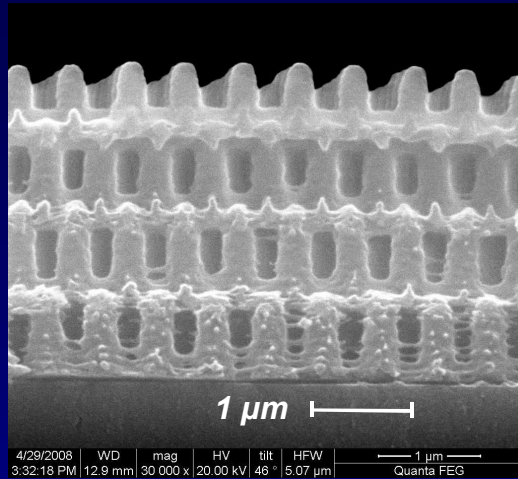
- Thicknesses up to ~ 30-50 μm obtained
- Construction is problematic:  
surface roughness, light exposure, collimation, solvent bake process, etc.
- Versatile technique for nanostructure synthesis!

## Nanostructure examples:

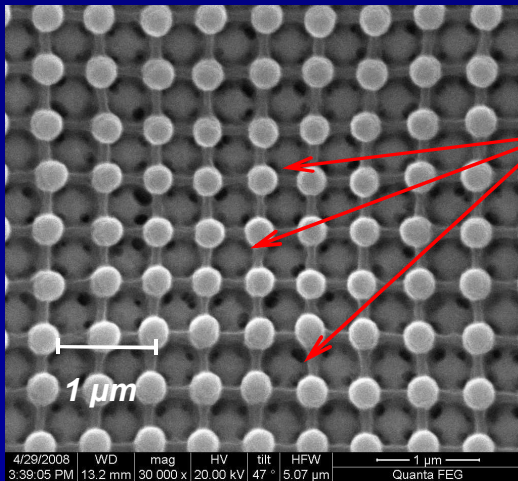


# PnP “fcc like” Nanostructure Geometry

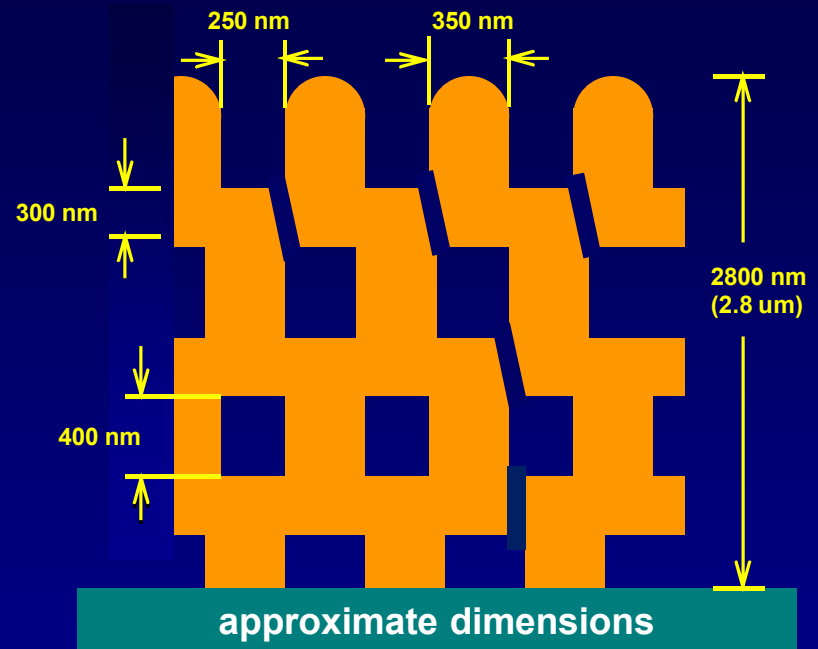
Side view



Top down



~ 150 nm diameter holes



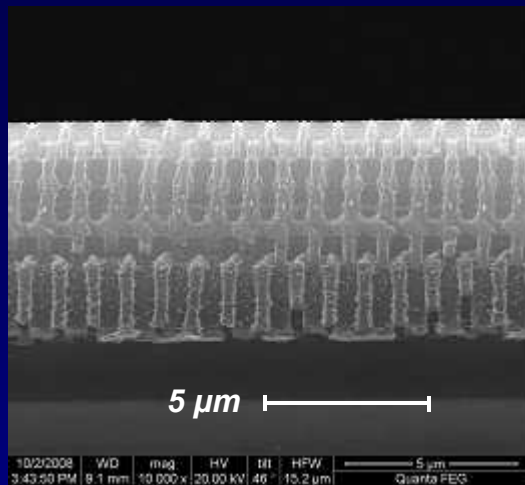
“fcc like”

- Phase mask:  $D = 400\text{nm}$ ,  $P = 550\text{nm}$   
(square post array)
- Aspect ratio  $L/d \sim 200$
- Torturous reactant path

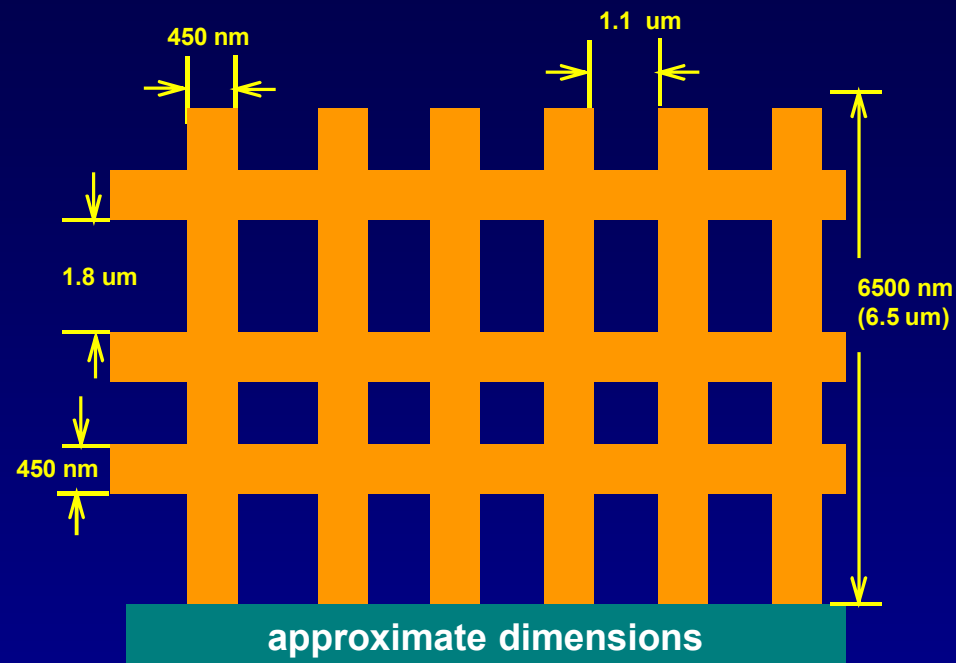
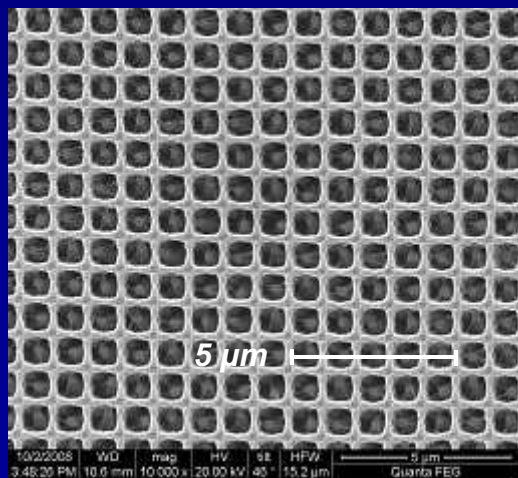


# PnP Inverse Square Array (ISA) Nanostructure Geometry

Side view



Top down

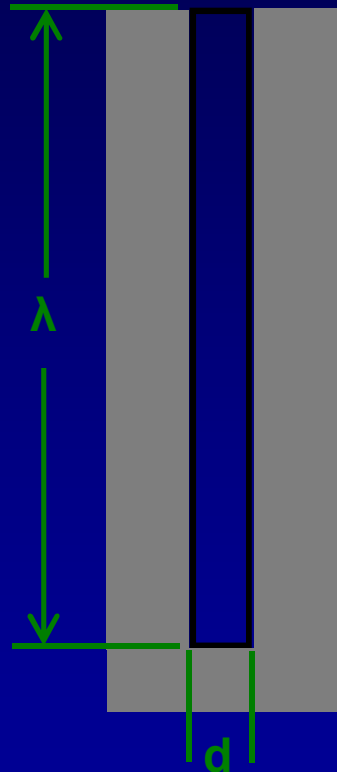


*“cubic like”*

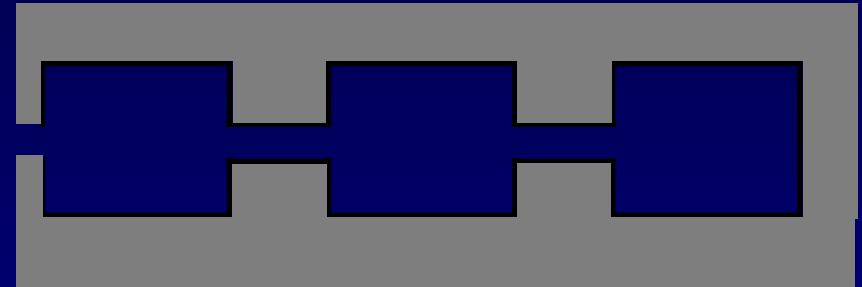
- Phase mask:  $D = 800\text{nm}$ ,  $P = 1000\text{nm}$   
(inverse square array)
- Aspect ratio  $L/d \sim 10$
- “Via” type reactant path

# Calculating Exposure Needed to Coat Nanostructures

“via” type structure



$$a = \lambda / d$$



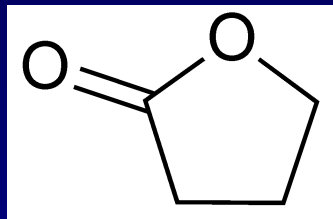
Put equation here....

$$(Pt)_{total} = S \sqrt{2\pi m k T} \left[ 1 + (19/4)a + (3/2)a^2 \right]$$

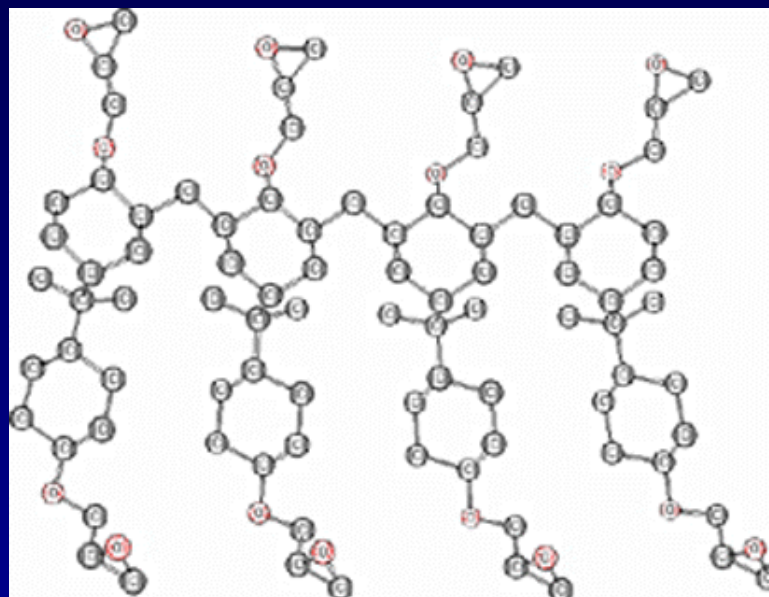
# SU8<sup>®</sup> Photopolymer Has Different Solvents

## SU8<sup>®</sup> SUPER MOLECULE

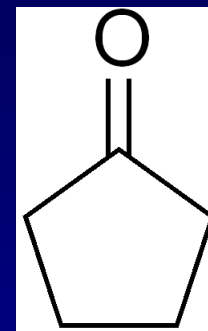
### Traditional SU8<sup>®</sup>



*γ-butyrolactone*  
boiling point = 204 °C



### 2000 Series SU8<sup>®</sup>

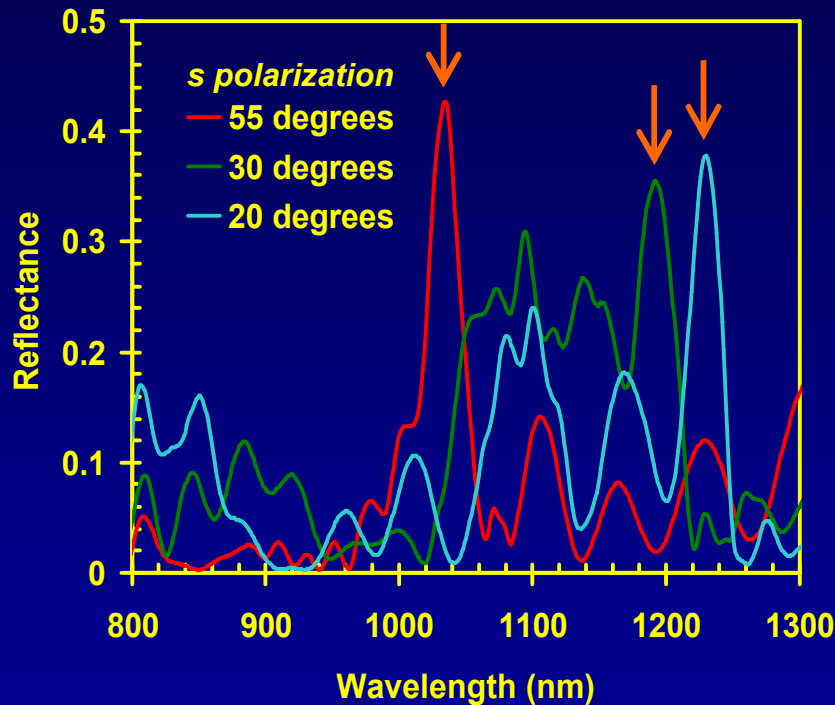


*cyclohexanone*  
boiling point = 130 °C

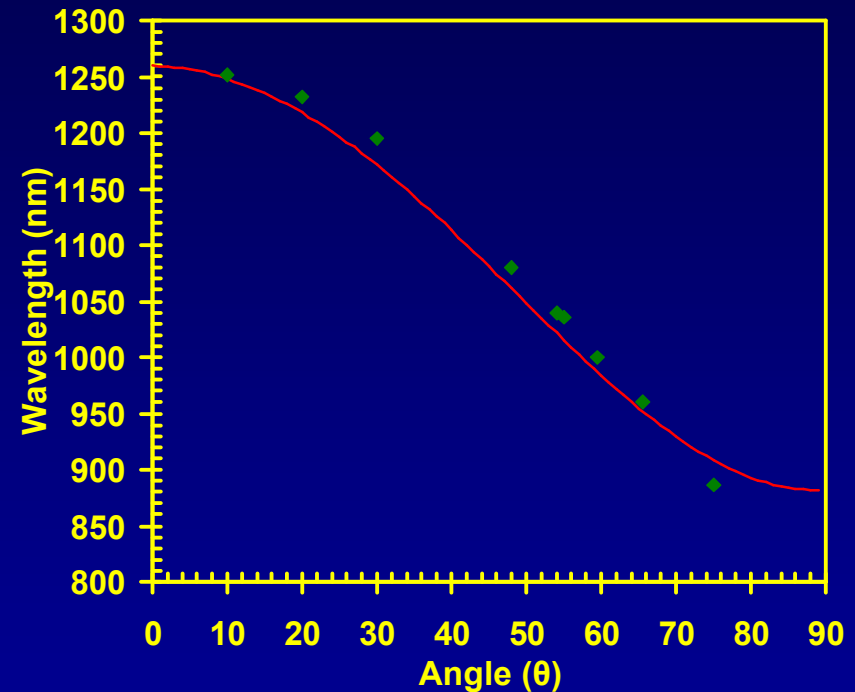
- SU8<sup>®</sup> super molecule has eight epoxide groups
- Uses photo-acid to initiate polymerization (365 nm)
- Solvent has profound effect on thermal stability

# Optical Diffraction Observed on “fcc like” PnP Nanostructure

## Optical diffraction



## Bragg-Snell curve



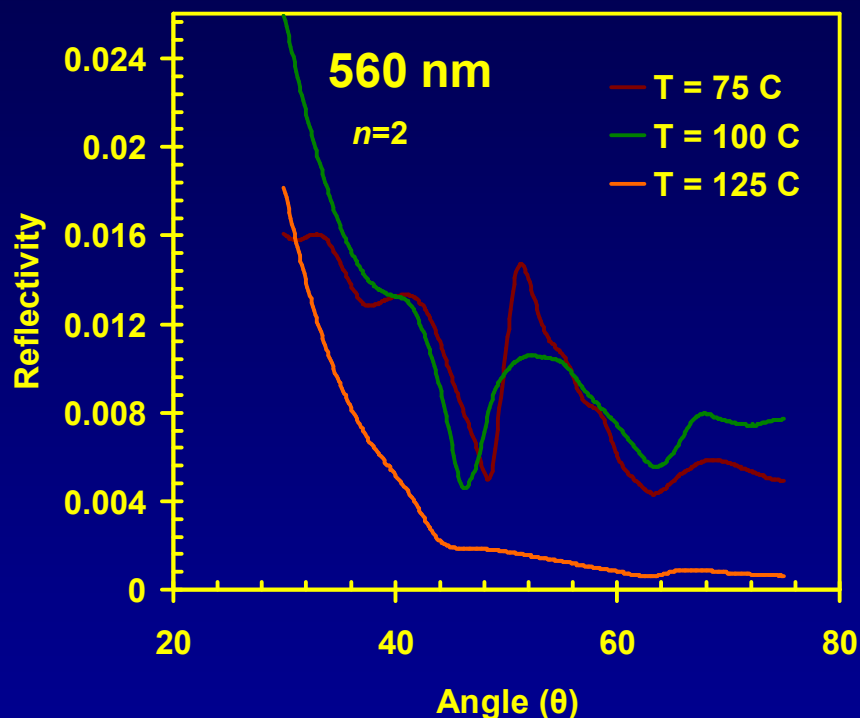
- Diffraction fits the Bragg-Snell law<sup>6</sup>
- $d = 470 \text{ nm}$ ,  $n_{\text{eff}} = 1.37$

Bragg-Snell equation

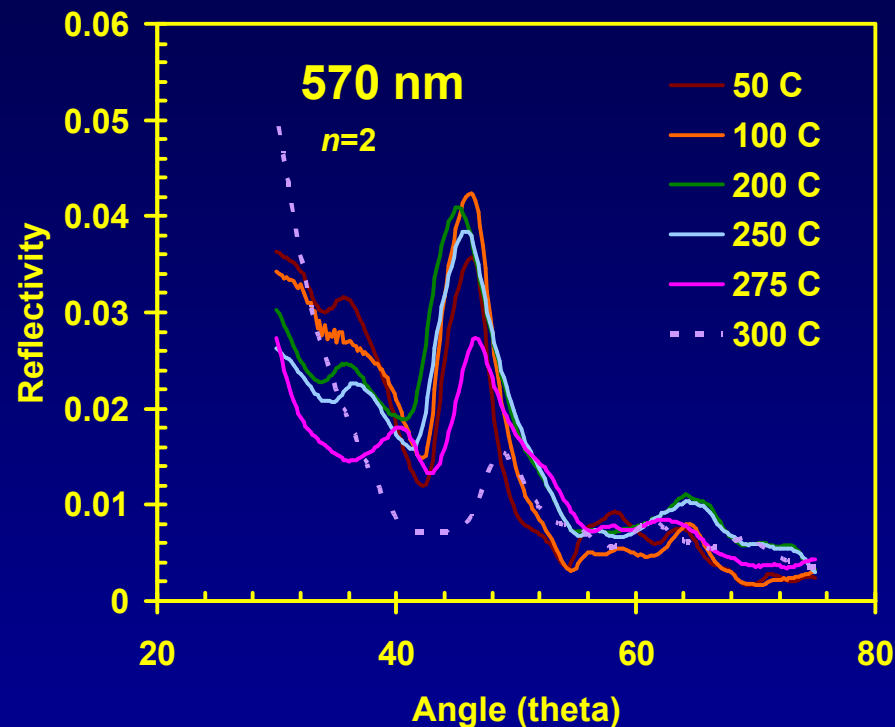
$$n\lambda = 2d\sqrt{n_{\text{eff}}^2 - \sin^2 \theta}$$

# Optical Diffraction Monitors Thermal Stability

## Traditional SU8®



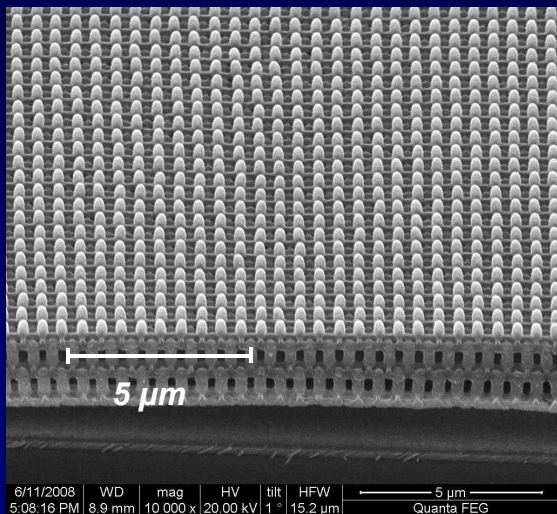
## 2000 Series SU8®



- Used variable angle spectroscopic ellipsometer (VASE) with hot stage.
- Dramatic differences in thermal stability!

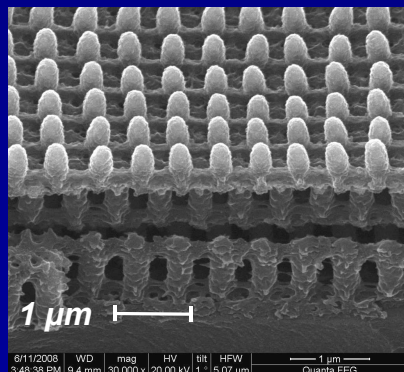
# Temp Stability of PnP Using Traditional SU8®

*“fcc like” array test structure*

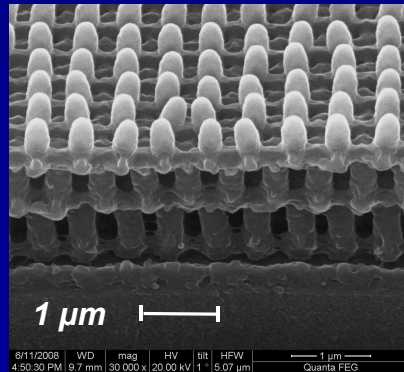


- Compared cleaved edges from same structure
- Heated under ALD reactor conditions
- By 125 °C structure shows signs of collapse
- ALD has to be performed at reduced temperature

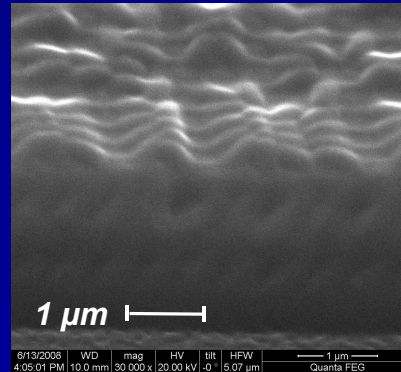
**No thermal treatment**



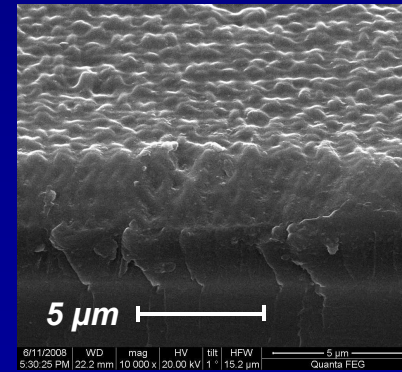
**85 °C for 24 hours**



**125 °C for 25 hours**



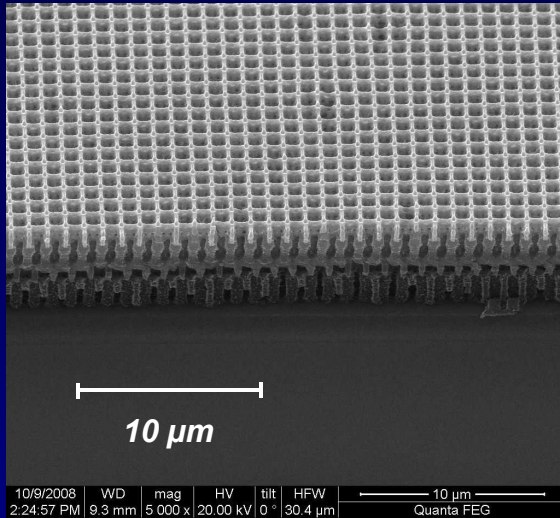
**200 °C for 64 hours**



*~ 200 Å Au/Pt Plasma sputtered on to non-conducting substrates*

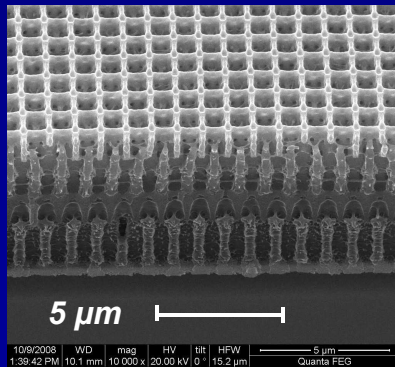
# Temp. Stability of PnP Using 2000 Series SU8<sup>®</sup>

ISA array test structure

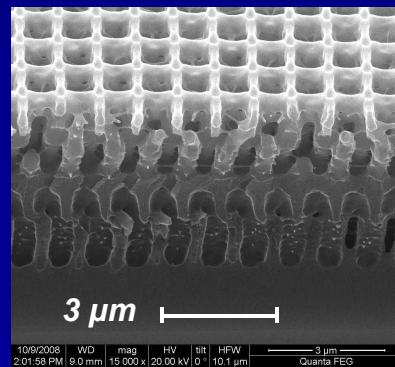


- Compared cleaved edges from same structure
- Heated under ALD reactor conditions
- At 300 °C structure shows no signs of collapse
- ALD can be performed at high temperatures!

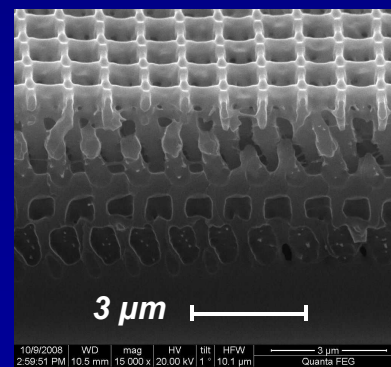
150 °C for 20 hours



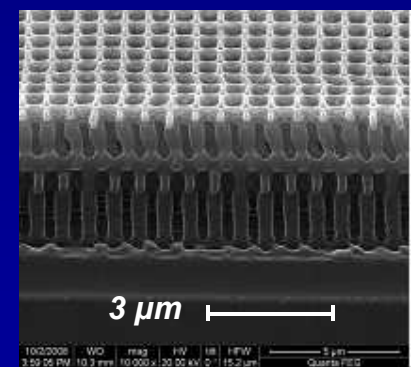
200 °C for 18 hours



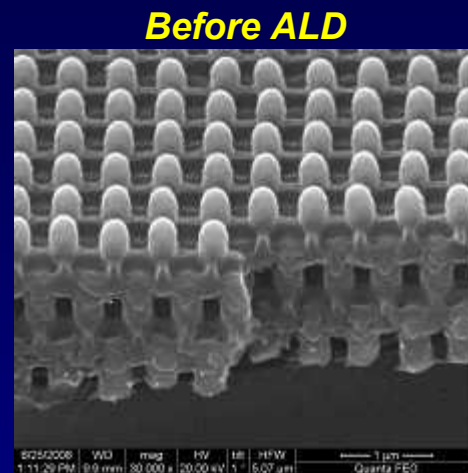
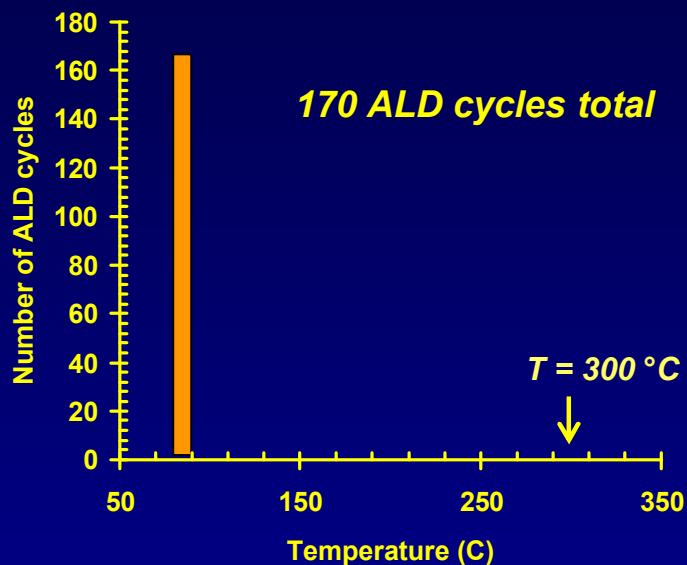
250 °C for 12 hours



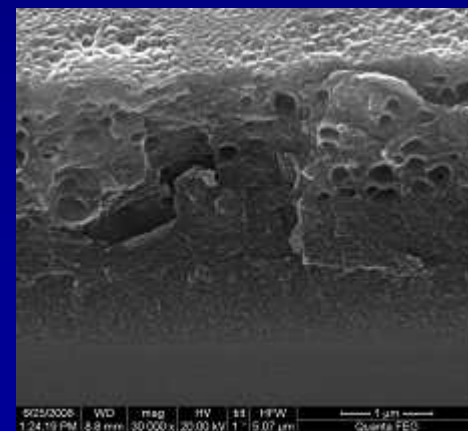
300 °C for 17 hours



# Temp. Stability on Structures Using Traditional SU8<sup>®</sup>, T = 85 °C



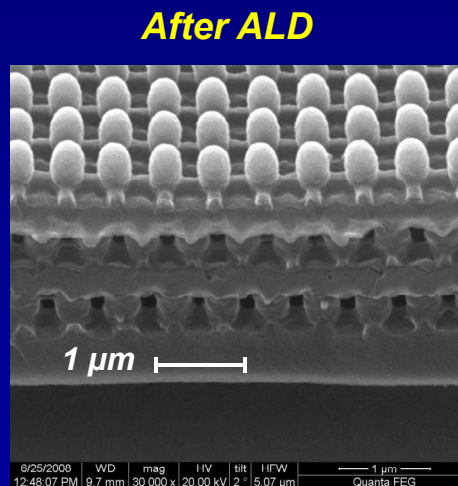
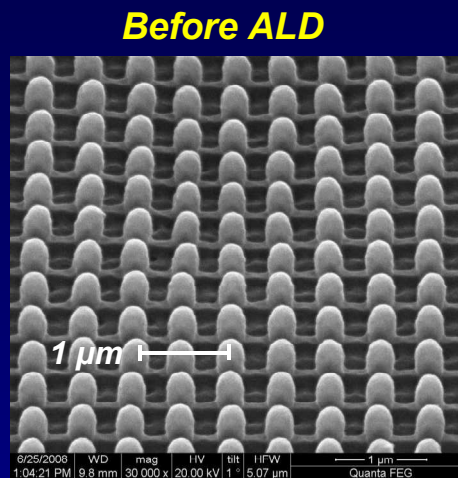
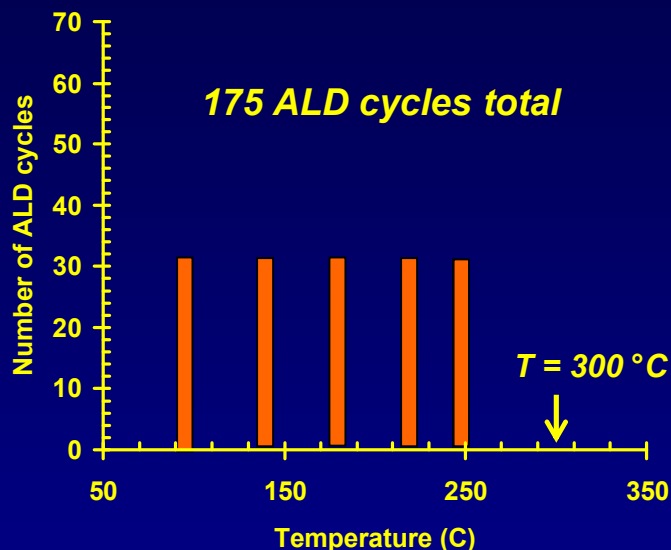
After ALD & anneal



- Run 170 ALD cycles of Al<sub>2</sub>O<sub>3</sub> at 85 °C<sup>7</sup>
- All cycles 2.5s pulse, 35s purge, TMA, H<sub>2</sub>O
- Heated nanostructure to 300 °C (6 °C/min)
- Observed some partial collapse

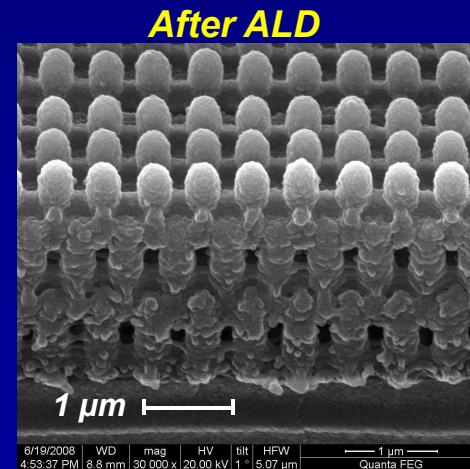
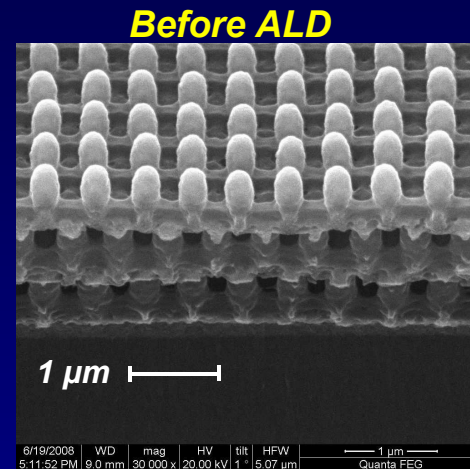
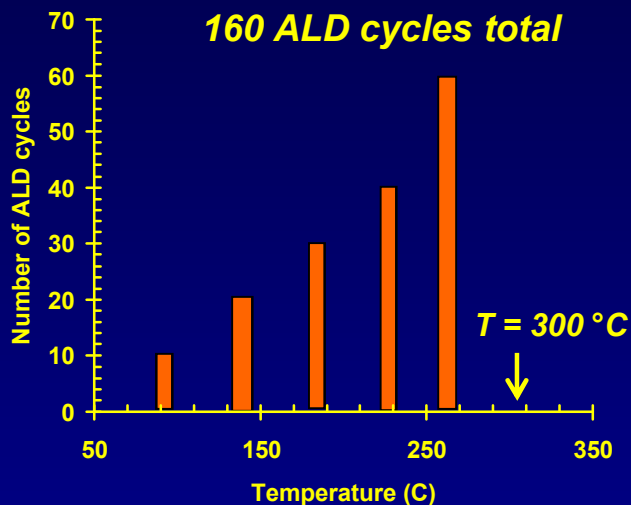


# Graded Temperature Constant ALD Cycles Using Traditional SU8<sup>®</sup> Photopolymer



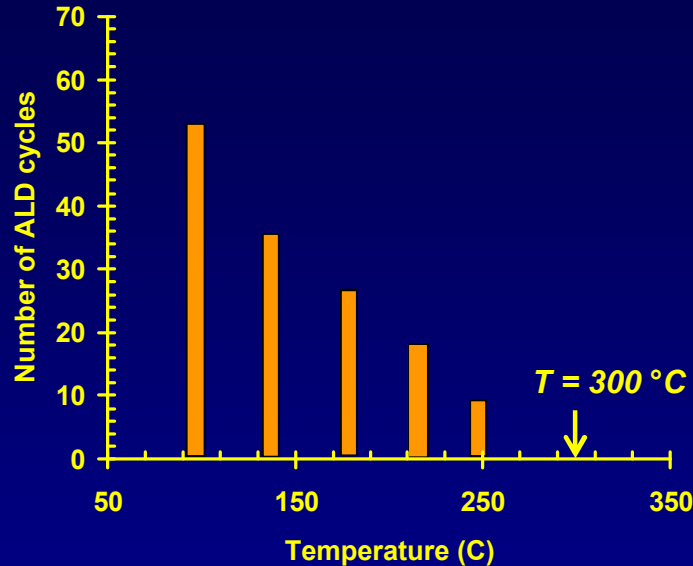
- Spread 175 cycles evenly over five temperatures
- All cycles 2.5 s pulse, 35 s purge
- SEM shows structure is intact
- Details of surface show “clumping”

# Graded Temperature Increasing ALD Cycles Using Traditional SU8<sup>®</sup> Photopolymer



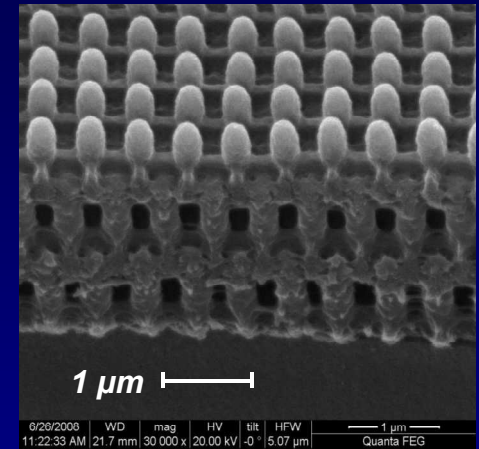
- Spread 160 cycles increasingly over five temperatures
- All cycles 2.5 s pulse, 35 s purge
- SEM shows very fuzzy coated structure

# Graded Temperature Decreasing ALD Cycles Using Traditional SU8<sup>®</sup> Photopolymer

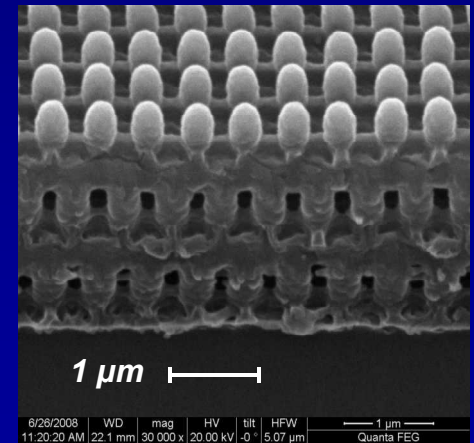


- Spread 175 cycles decreasingly over five temperatures
- All cycles 2.5s pulse, 35s purge
- Smooth deposition on surface of polymer
- The structure can be templated

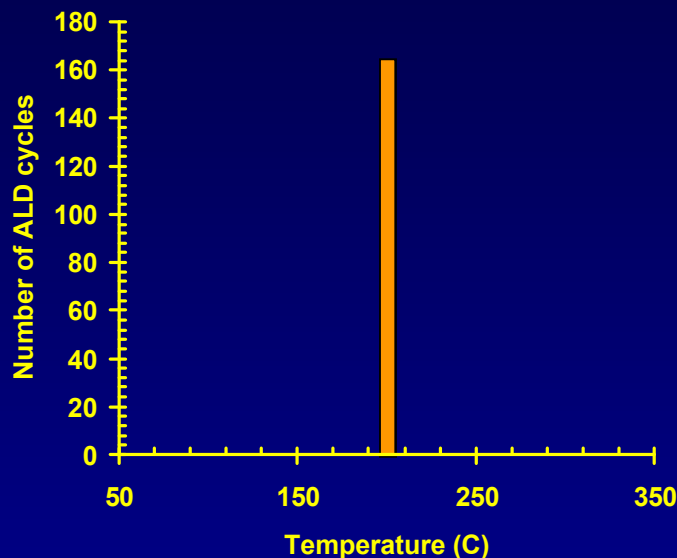
Before ALD



After ALD

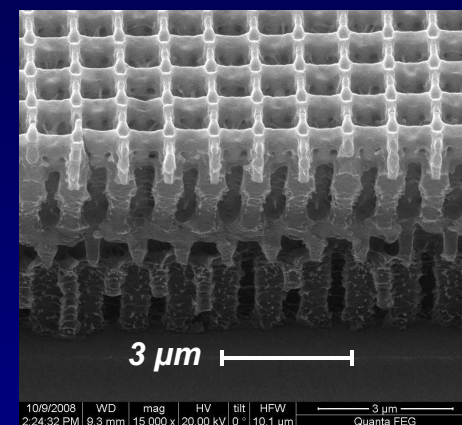


# Constant Temperature ALD Cycles Using 2000 Series SU8<sup>®</sup> Photopolymer, T = 200 °C

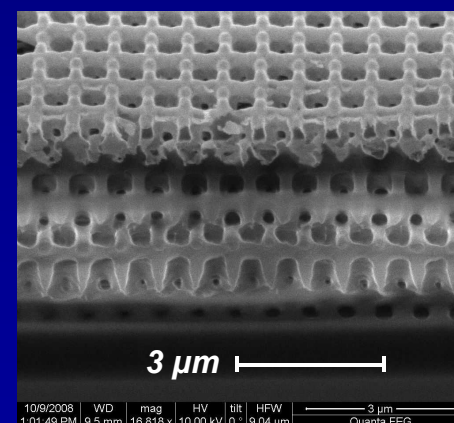


- Ran 175 cycles *at constant* temperature
- All cycles 2.5s pulse, 35s purge
- Smooth deposition on surface of polymer
- The structure can be templated

**Before ALD**

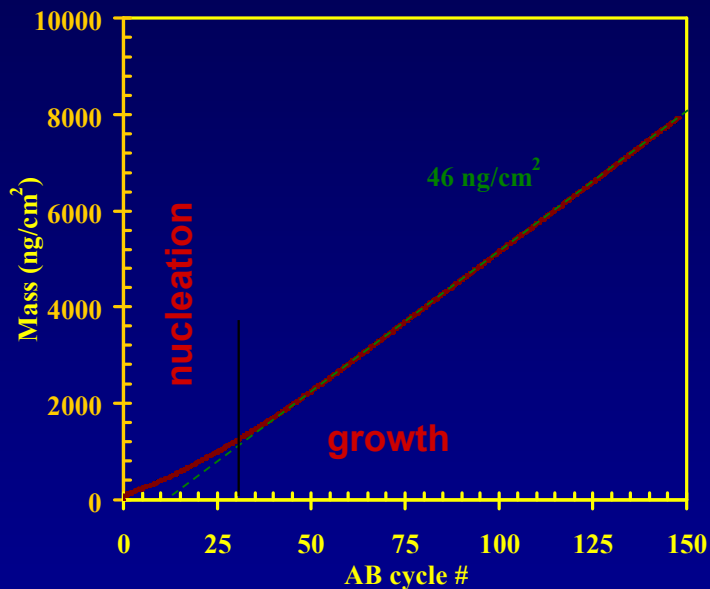


**After ALD**



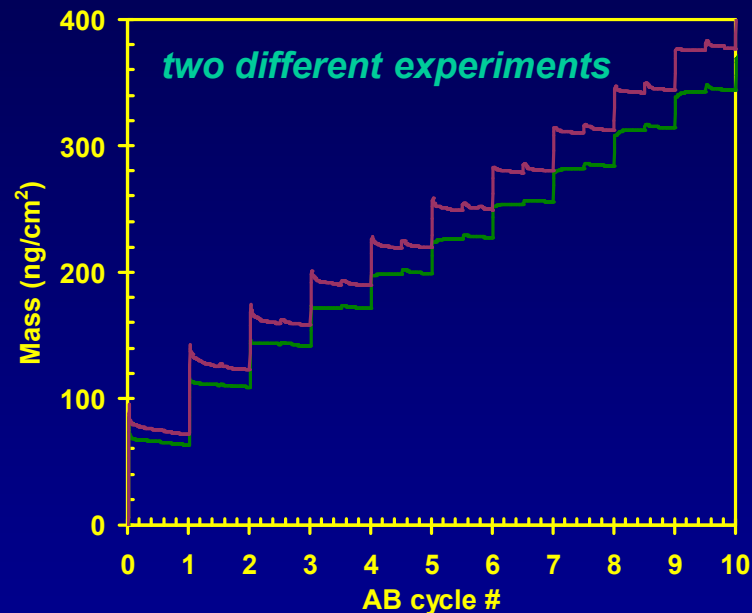
# QCM Results of ALD $\text{Al}_2\text{O}_3$ on Traditional SU8<sup>®</sup> Photopolymer

## QCM of $\text{Al}_2\text{O}_3$ ALD on SU-8



ALD  $\text{Al}_2\text{O}_3$   
growth rate  
1.1 Å/cycle  
~ 36 ng/cm<sup>2</sup>

## QCM of nucleation region



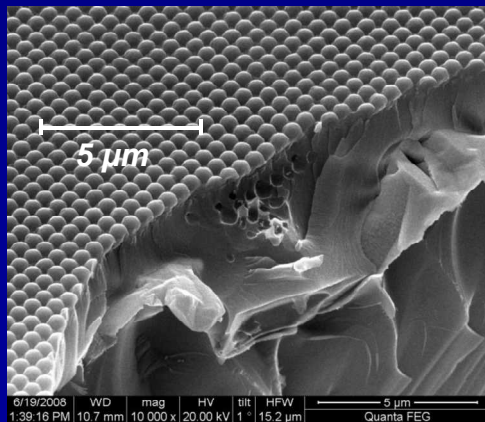
- $T_{\text{react}} = 85\text{ }^\circ\text{C}$ ,  $P = 1\text{ Torr}$
- 2s pulse, 35s purge TMA and  $\text{H}_2\text{O}$
- Back-purged QCM<sup>8</sup>

- Short nucleation observed
- Small TMA solubility in polymer
- Linear after ~ 30 AB cycles

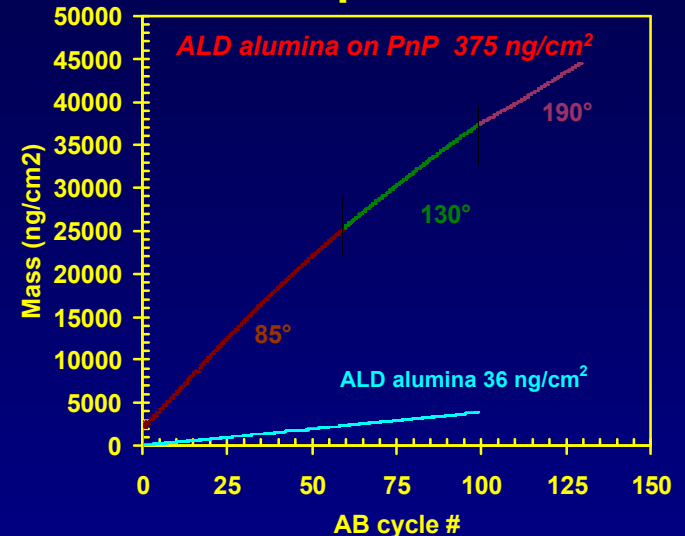
# QCM Results of ALD $\text{Al}_2\text{O}_3$ on Nanostructure Using Traditional SU8<sup>®</sup>, $T = 85^\circ\text{C}$

- Spun and developed PnP polymer structure on QCM crystal<sup>9</sup>
- ~ x10 mass enhancement
- SEM observed no 3D structure
- Odd  $\text{H}_2\text{O}$  pulses at low temperature

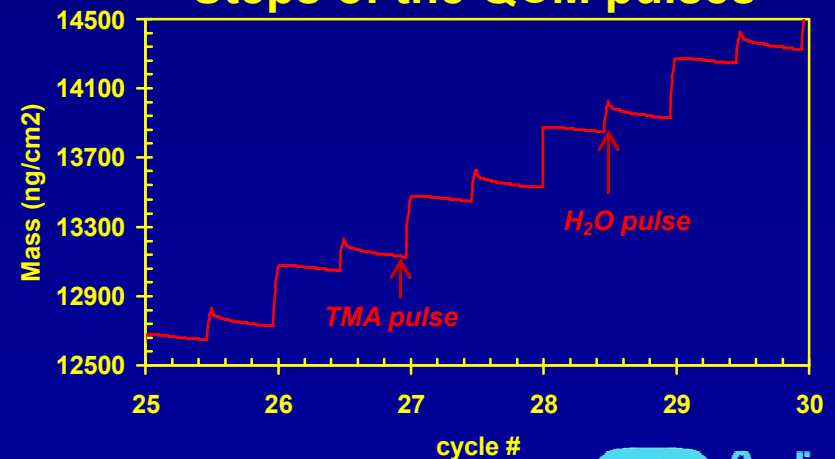
SEM of “fcc like” PnP on QCM crystal



Graded temperature QCM

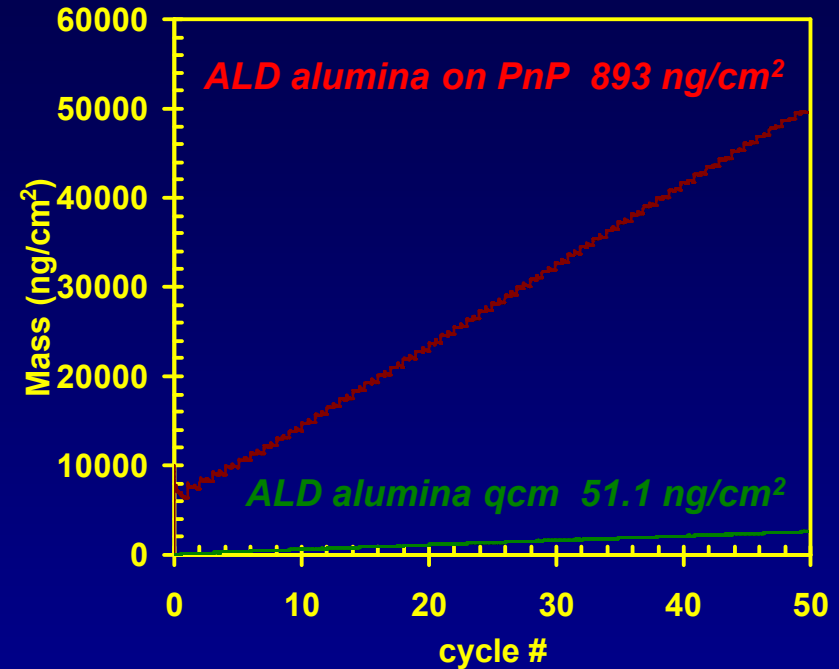
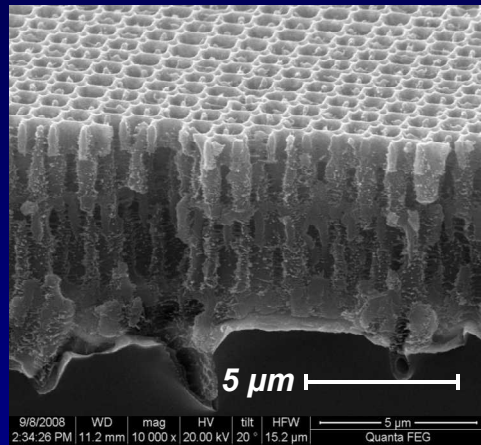


Steps of the QCM pulses



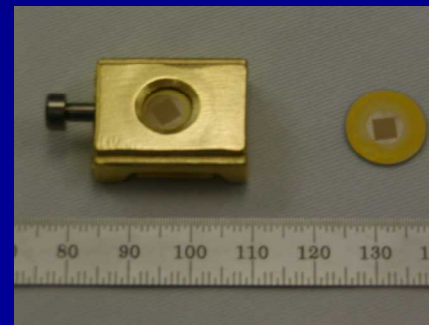
# QCM Results of ALD $\text{Al}_2\text{O}_3$ on Nanostructure Using 2000 Series SU8<sup>®</sup>, $T = 85^\circ\text{C}$

SEM of ISA PnP on QCM crystal



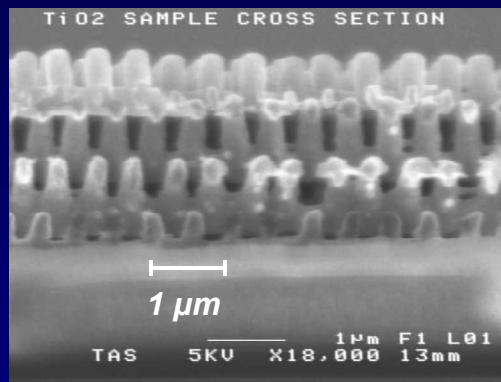
- Used ISA PnP structure on QCM
- SEM observed 3D structure
- ~ x17 mass enhancement
- “cob-webs” in structure could increase surface area

QCM with ISA PnP



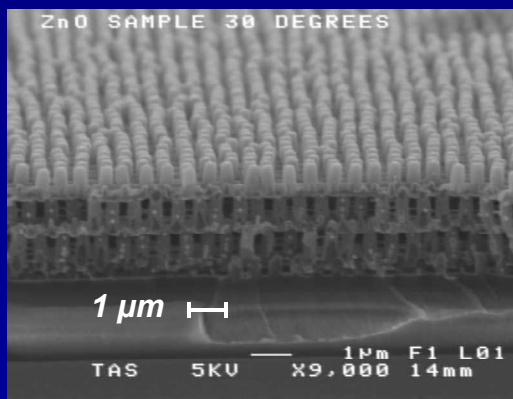
# SEM Examples of Coated PnP Structures

*TiO<sub>2</sub> ALD template decreasing  
ALD cycles*

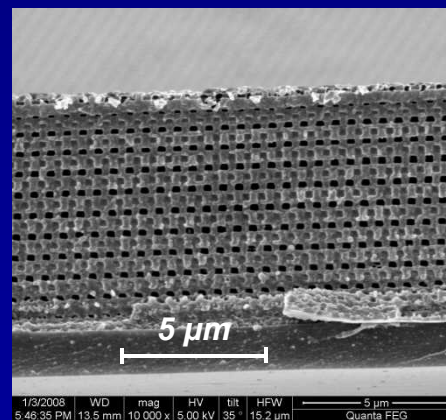


- Have deposited ALD TiO<sub>2</sub>, ZnO, ZrO<sub>2</sub> and Pt metal
- Graded temperature approach worked with TiO<sub>2</sub>
- Detecting ALD conformality on nanostructures using TEM analysis was inconclusive

*~ 150 Å ZnO on Al<sub>2</sub>O<sub>3</sub> ALD  
templated nanostructure  
(decreasing cycles)*



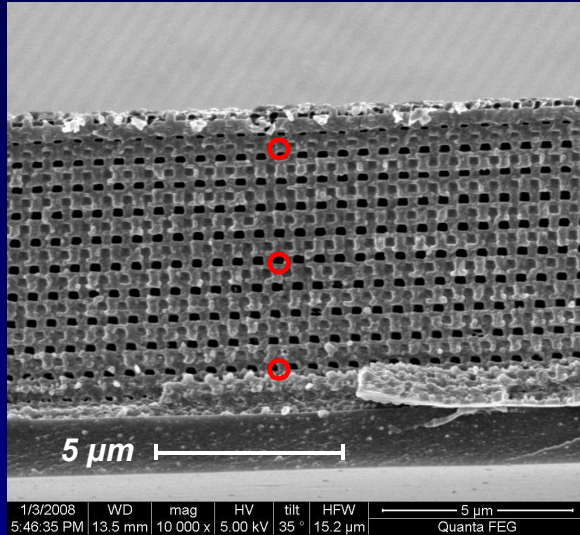
*“fcc like’ lattice with ~ 200  
Å Pt ALD<sup>10</sup>*





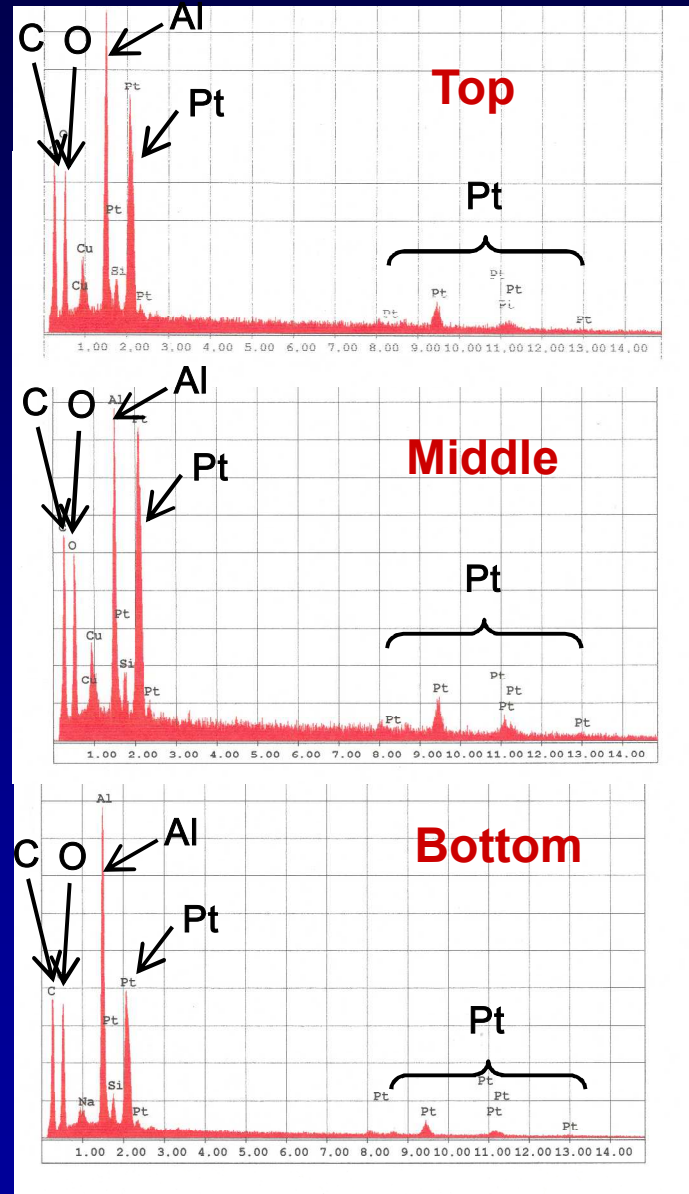
# Micro-EDX Shows Presence of Pt Metal

## Pt coated Al<sub>2</sub>O<sub>3</sub> templated PnP



- Spot size of EDX was ~ 500nm
- C, O, Al and Pt observed in spectrum
- Bottom shows different ratios of Al/Pt

*EDX = energy dispersive x-ray*



# Conclusions:



- The predictive and general PnP formed nanostructures can be used as templates for ALD coatings
- PnP nanostructures made from Traditional SU8<sup>®</sup> collapse at < 125 °C
- PnP nanostructures made from 2000 series SU8<sup>®</sup> are stable to temperatures > 200 °C
- Graded temperature ALD is necessary for Traditional SU8<sup>®</sup>
- TiO<sub>2</sub>, ZnO, and Pt metal ALD have been deposited on templated nanostructures
- QCM indicates short nucleation of Al<sub>2</sub>O<sub>3</sub> ALD on SU8<sup>®</sup>
- PnP structures on QCM crystals showed dramatic surface area enhancement